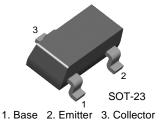
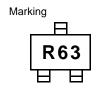


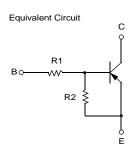
KSR2113

Switching Application (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor ($R_1=2.2K\Omega$, $R_2=47K\Omega$)
- Complement to KSR1113







PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

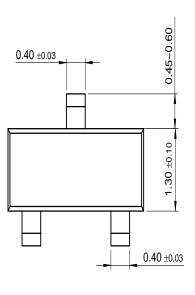
| Symbol | Parameter | Value | Units |
|------------------|-----------------------------|-----------|-------|
| V_{CBO} | Collector-Base Voltage | -50 | V |
| V _{CEO} | Collector-Emitter Voltage | -50 | V |
| V _{EBO} | Emitter-Base Voltage | -10 | V |
| I _C | Collector Current | -100 | mA |
| P _C | Collector Power Dissipation | 200 | mW |
| T _J | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | -55 ~ 150 | °C |

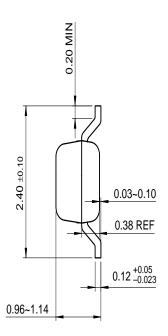
Electrical Characteristics T_a=25°C unless otherwise noted

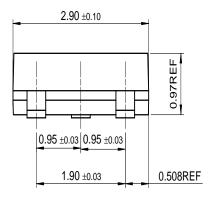
| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|--------------------------------|--------------------------------------|---|-------|-------|-------|-------|
| BV _{CBO} | Collector-Base Breakdown Voltage | I_{C} = -10 μ A, I_{E} =0 | -50 | | | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | $I_C = -100 \mu A, I_B = 0$ | -50 | | | V |
| I _{CBO} | Collector Cutoff Current | V_{CB} = -40V, I_{E} =0 | | | -0.1 | μΑ |
| h _{FE} | DC Current Gain | V_{CE} = -5V, I_{C} = -5mA | 68 | | | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I_{C} = -10mA, I_{B} = -0.5mA | | | -0.3 | V |
| f _T | Current Gain Bandwidth Product | V_{CE} = -10V I_{C} =-5mA | | 200 | | MHz |
| C _{ob} | Output Capacitance | V _{CB} = -10V, I _E =0 f=1.0MHz | | 5.5 | | pF |
| V _I (off) | Input Off Voltage | V_{CE} = -5V, I_{C} = -100 μ A | -0.5 | | | V |
| V _I (on) | Input On Voltage | V_{CE} = -0.2V, I_{C} = -10mA | | | -1.1 | V |
| R ₁ | Input Resistor | | 1.5 | 2.2 | 2.9 | ΚΩ |
| R ₁ /R ₂ | Resistor Ratio | | 0.042 | 0.047 | 0.052 | |

Package Demensions

SOT-23







Dimensions in Millimeters

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|--------------------------|---------------------------|---|
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